

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

MCH6423 — General-Purpose Switching Device **Applications**

Features

• 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱ _D		2	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	8	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (1200mm ² X0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =60V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =1A	1.3	2.2		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=1A, VGS=10V		170	220	mΩ
	R _{DS} (on)2	ID=0.5A, VGS=4V		210	300	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		220		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		28		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		20		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		8		ns
Rise Time	tr	See specified Test Circuit.		5.3		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		26		ns
Fall Time	tf	See specified Test Circuit.		21		ns

Marking : KX

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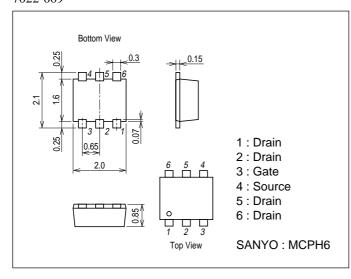
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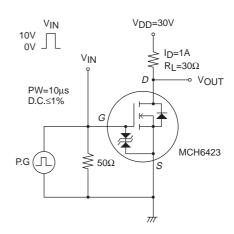
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Total Gate Charge	Qg	VDS=30V, VGS=10V, ID=2A		6.4		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =10V, I _D =2A		1.1		nC
Gate-to-Drain "Miller" Charge	Qgd	VDS=30V, VGS=10V, ID=2A		1.1		nC
Diode Forward Voltage	VSD	IS=2A, VGS=0V		0.85	1.2	V

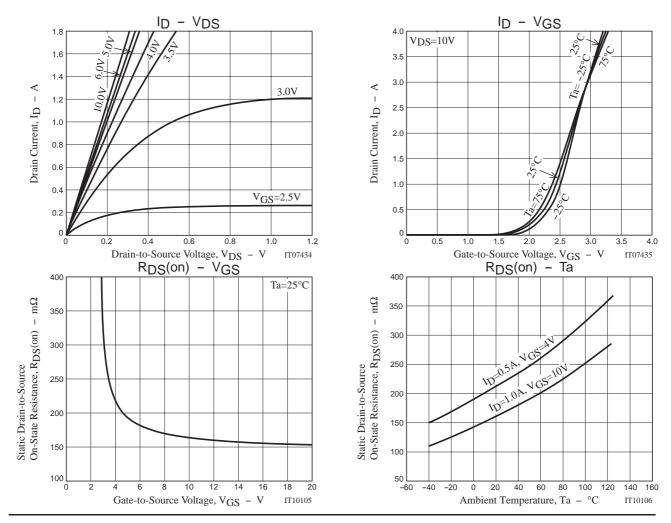
Package Dimensions

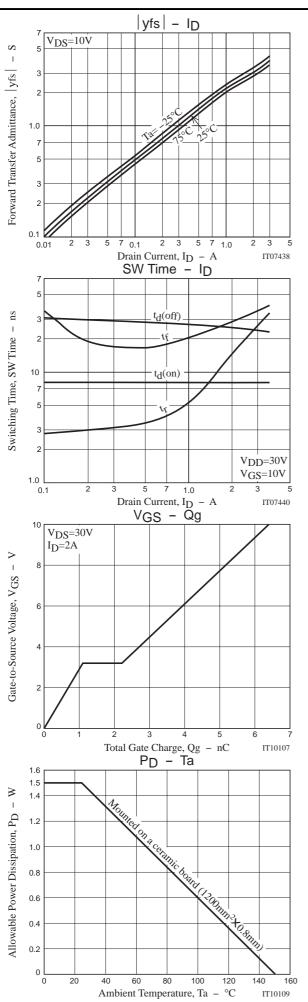
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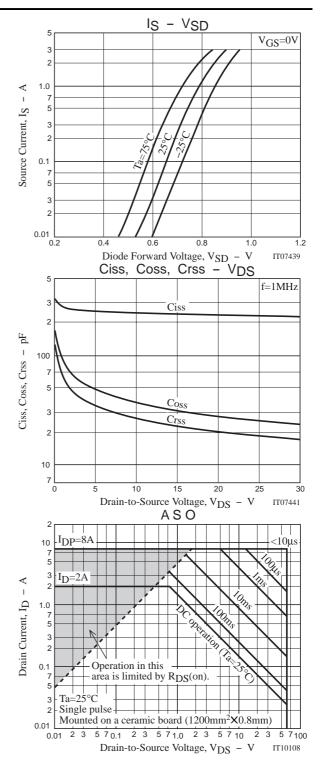


Switching Time Test Circuit









Note on usage : Since the MCH6423 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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